# NSN 5961-00-064-2209

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.375 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

## Semiconductor Material:

Germanium

# Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 55.0 breakdown voltage, collector-to-emitter, base open and 30.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

3.00 amperes base current, dc and 7.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector

# Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release3811 professional/industrial association specification

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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